

PFR850→856

FAST RECOVERY RECTIFIER DIODE

PRELIMINARY DATASHEET

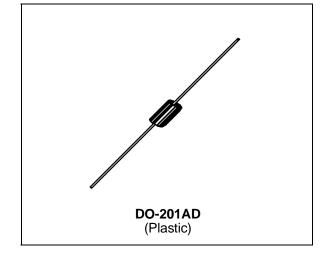
- LOW FORWARD VOLTAGE DROP
- HIGH SURGE CURRENT CAPABILITY

APPLICATIONS

- AC-DC POWER SUPPLIES AND CONVERTERS
- FREE WHEELING DIODES, etc.

DESCRIPTION

Their high efficiency and high reliability combined with small size and low cost make these fast recovery rectifier diode very attractive components for many demanding applications.



Symbol	Parameter	Value	Unit			
IFRM	Repetive peak forward current	100	А			
lf (AV)	Average forward current*	$\begin{array}{l} T_a = 90^{\circ}C\\ \delta = 0.5 \end{array}$	3	A		
IFSM	Surge non repetitive forward current	t _p = 10ms Sinusoidal	100	А		
P _{tot}	Power dissipation *	3.5	W			
T _{stg} Tj	Storage and junction temperature range- 40 to + 175- 40 to + 175					
TL	Maximum lead temperature for soldering during 10s at 4mn from case230					

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	PFR					Unit	
Symbol			851	852	854	856	Onit	
Vrrm	Repetitive peak revrse voltage	50	100	200	400	600	V	
Vrsm	Non repetitive peak reverse voltage	75	150	250	450	650	V	

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THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th (j - a)}	Junction-ambient*	25	°C/W

* On infinite heatsink with 10mm lead lengh.

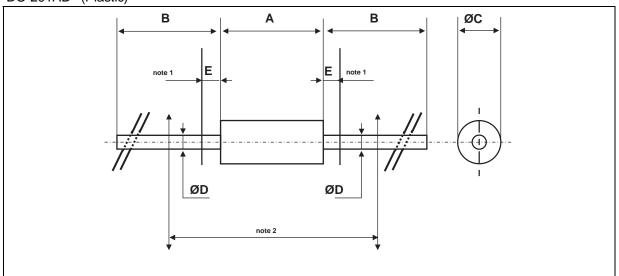
STATIC ELECTRICAL CHARACTERISTICS

Synbol		Test Conditions Min. Typ.						
I _R	$T_j = 25^{\circ}C$	$V_{R} = V_{RRM}$			10	μA		
	$T_j = 100^{\circ}C$				250			
VF	T _j = 25°C	I _F = 3A			1.25	V		

RECOVERY CHARACTERISTICS

Symbol		Min.	Тур.	Max.	Unit		
trr	Tj = 25℃	$I_F = 1A$	PRF 850→854			150	ns
	$V_R = 30V$	di _F /dt = - 25A/µs	PRF 856			200	
I _{RM}	Tj = 25℃	$I_F = 1A$				2	А
	$V_R = 30V$	di⊧/dt = -25A/µs					

PACKAGE MECHANICAL DATA DO-201AD (Plastic)



		DIMEN	SIONS		
REF.	F. Millimeters		Inches		NOTES
	Min.	Max.	Min.	Max.	
A		9.50		0.374	1 - The lead diameter \varnothing D is not controlled over zone E
В	25.40		1.000		2 - The minimum axial lengh within which the device may be
ØC		5.30		0.209	placed with its leads bent at right angles is 0.59"(15 mm)
ØD		1.30		0.051	
E		1.25		0.049	

Marking: type number, white band indicate cathode

Cooling method: by convection (method A)

Weight: 1g

Date code

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